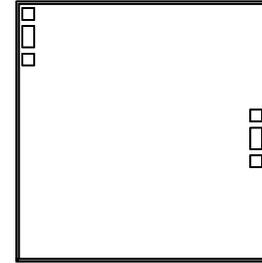**MMIC DIE**

X3 Frequency Multiplier

CY3-64-D+

50Ω   Output 30 to 60 GHz

THE BIG DEAL

- Wideband Output from: 30 to 60 GHz
- Outstanding Fundamental and Close-in Harmonic Suppression:
  - F1: +30 dBc Typ.
  - F2: +33 dBc Typ.
  - F4: +42 dBc Typ.
- Input Drive Level: +12 to +19 dBm
- Conversion Loss: 21 dB Typ.

+RoHS Compliant
The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

SEE ORDERING INFORMATION ON THE LAST PAGE

APPLICATIONS

- 5G MIMO and Back Haul Radio Systems
- Satellite Communications
- Test and Measurement Equipment
- Radar, EW, and ECM Defense Systems

PRODUCT OVERVIEW

Mini-Circuits' CY3-64-D+ is a wideband MMIC Frequency Tripler, converting input frequencies from 10 to 20 GHz into output frequencies from 30 to 60 GHz. Its wide output range makes this model suitable for broadband systems as well as a wide variety of narrow-band applications. The CY3-64-D+ die utilizes GaAs HBT technology and is suitable for chip and wire assemblies.

KEY FEATURES

Feature	Advantages
Broadband, 30 to 60 GHz output	With an output frequency range spanning 30 to 60 GHz, this multiplier supports broadband applications such as defense and instrumentation as well as a wide range of narrowband system requirements including 5G.
Excellent fundamental and harmonic suppression: • F1, +30 dBc Typ. • F2, +33 dBc Typ. • F4, +42 dBc Typ.	Harmonic and fundamental filtering requirements are dramatically simplified due to the high suppression resulting from internal cancellation within the diode configuration.
Wide input power range +12 to +19 dBm	Wide input power signal range accommodates different input signal levels while still maintain a low conversion loss
Unpackaged Die	Enable user to integrate it directly into hybrids chip and wire assemblies

X3 Frequency Multiplier   **CY3-64-D+**

50Ω   Output 30 to 60 GHz

ELECTRICAL SPECIFICATIONS[1] AT +25°C AND Z$_O$ = 50Ω, UNLESS NOTED OTHERWISE

Parameter		Condition (GHz)	Min.	Typ.	Max.	Unit
Multiplication Factor				3		
Frequency Range, Input (F1)			10		20	GHz
Frequency Range, Output (F3)			30	-	60	GHz
Input Power[4]			+12	+18	+19	dBm
Conversion Loss (F3)[3]		10-12		20.0		dB
		12-14		19.3		
		14-16		20.7		
		16-18		22.2		
		18-20		23.8		
Harmonic Output[2,3]	F1	10-12		37		dBc
		12-14		34		
		14-16		30		
		16-18		26		
		18-20		22		
	F2	10-12		49		dBc
		12-14		35		
		14-16		33		
		16-18		28		
		18-20		22		
	F4	10-12		44		dBc
		12-14		47		
		14-16		42		
		16-18		35		
		18-20		43		

1. Electrical specifications are measured by attaching the die on Mini-Circuits Die Characterization Test Board. Trace and connector losses are de-embedded. Specifications Include the effect of bond wires.
2. Harmonics of input frequency below the power of F3.
3. F1=Input Frequency, F2=Second Harmonic, F3=Fundamental Output, F4=Fourth Harmonic
4. All specifications are measured with RF input power = +18 dBm.

MAXIMUM RATINGS[5]

Parameter	Ratings
Operating Temperature	-40°C to +85°C
Storage Temperature	+20°C to +35°C
RF Input Power	+22 dBm

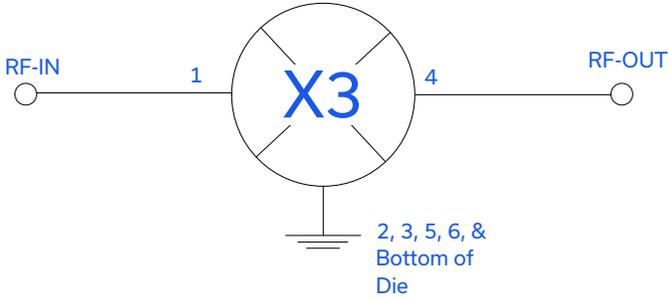5. Permanent damage may occur if any of these limits are exceeded.
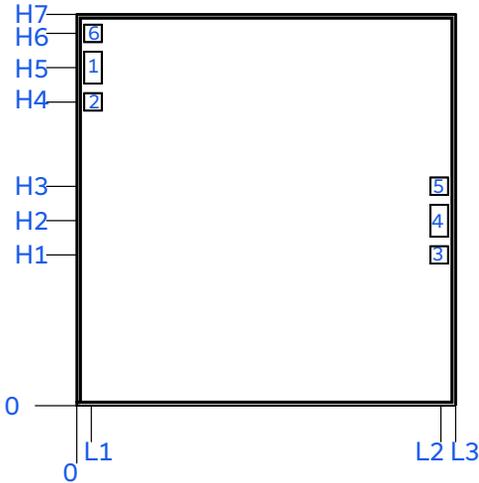
MMIC DIE
X3 Frequency Multiplier
CY3-64-D+
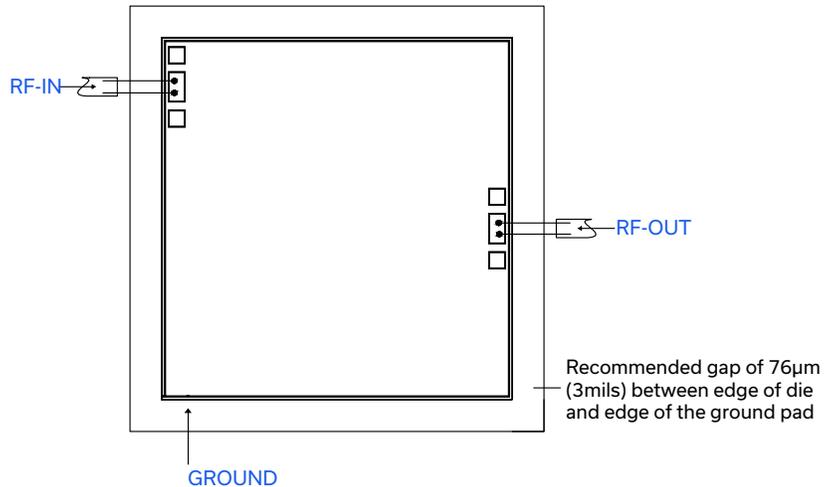### 50Ω   Output 30 to 60 GHz

SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION

RF-IN   1   **X3**   4   RF-OUT

2, 3, 5, 6, & Bottom of Die

Function	Pad Number	Description
RF-IN	1	RF-Input pad
RF-OUT	4	RF-Output pad
Ground	2, 3, 5 & 6	The bond pads are connected to back-side through vias and do not require wire-bond connections to ground.

DIE DIMENSIONS

ASSEMBLY DIAGRAM

RF-IN

RF-OUT

Recommended gap of 76µm (3mils) between edge of die and edge of the ground pad

GROUND

Note: bond wires should be as short as possible

DIMENSIONS µm, TYPICAL

L1	L2	L3	H1	H2	H3	H4	H5	H6	H7
81.0	2019.0	2100.0	836.0	1026.0	1217.0	1684.0	1875.0	2066.0	2170.0

Thickness	Die Size	Pad Size 1 & 4	Pad Size 2, 3, 5 & 6
100	2100 x 2170	92 x 172	92 x 92

CHARACTERIZATION CIRCUIT

Keysight PNA-X N5247B
Network Analyzer with 110 GHz Frequency Extender

PORT 3   R3   RCVR C   PORT 1   PORT 2

Freq. Ext.

6dB

ZVA-0.5W303G+

VDD=12V
IDD=460mA

3dB

Die TB

2 x (ZCDC20-E18653+)

RF-IN   X3   RF-OUT
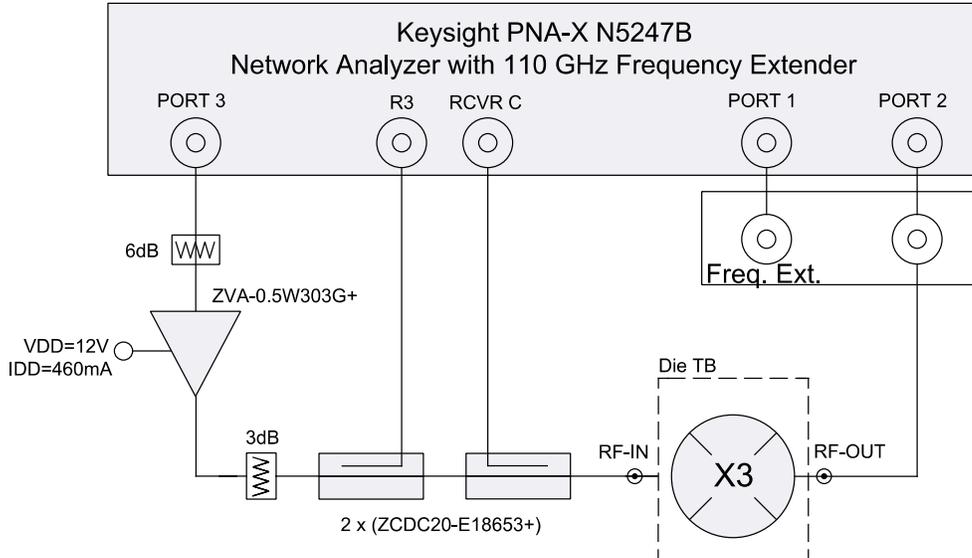
6 dB attenuator P/N BW-E6-1W653+
3 dB attenuator P/N BW-E3-1W653+

Note: DUT attached on a Mini-Circuits Die Characterization Test Board. Conversion Loss and Harmonic Output are measured using PNA-X Network Analyzer.

Test Condition: For CL and Harmonic Rejection: RF input power: +12 to +19dBm.

ASSEMBLY PROCEDURE

1. Storage
   Die should be stored in a dry nitrogen purged desiccators or equivalent.

2. ESD
   MMIC HBT Multiplier die are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be open in clean room conditions at an appropriately grounded anti-static workstation.

3. Die Handling and Attachment
   Devices need careful handling using correctly designed collets, it is recommended to handle the chip along the edges with a custom design collet. The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are Ablestik 84-1 LMISR4 or equivalents. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition.

4. Wire Bonding
   Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the die gold bond pads. Thermo-sonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1mil diameter. Bonds must be made from the bond pads on the die to the packaged or substrate. All bond wire length and bond wire height should be kept as short as possible unless specified by the Assembly Drawing to minimize performance degradation due to undesirable series inductance

TYPICAL PERFORMANCE CURVES

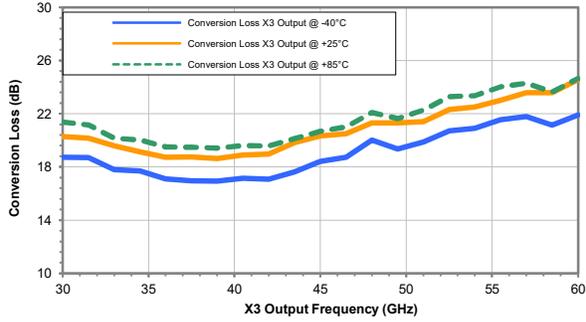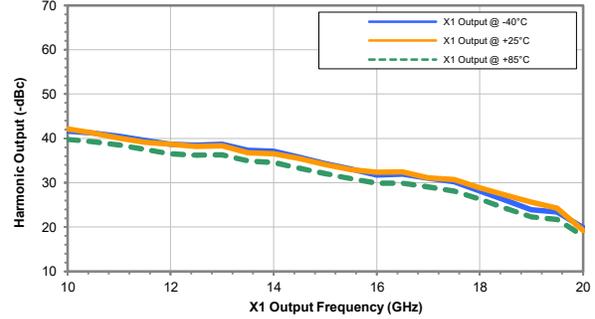Note: Harmonics data is presented as the harmonic of input frequency below the power of F3

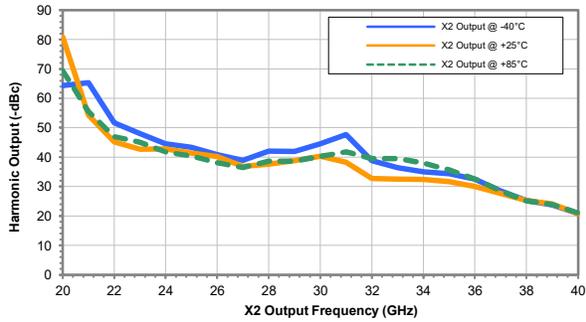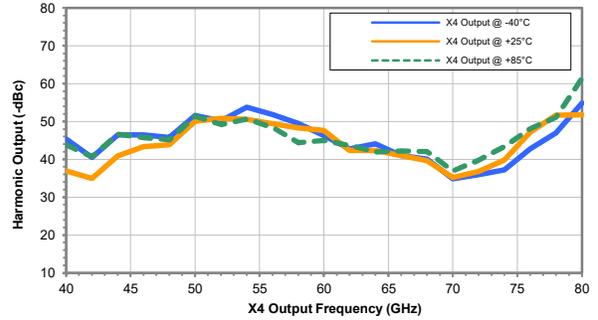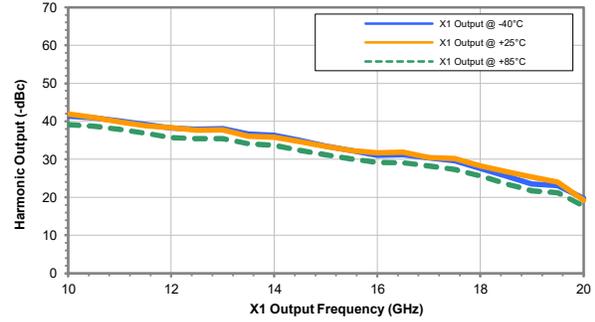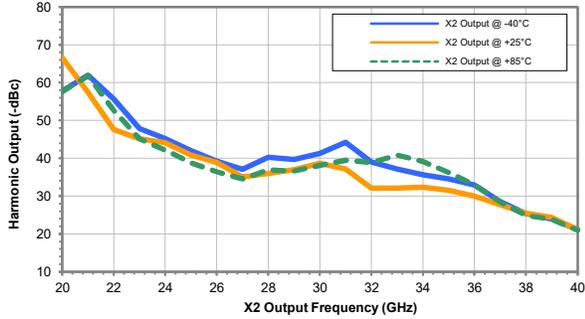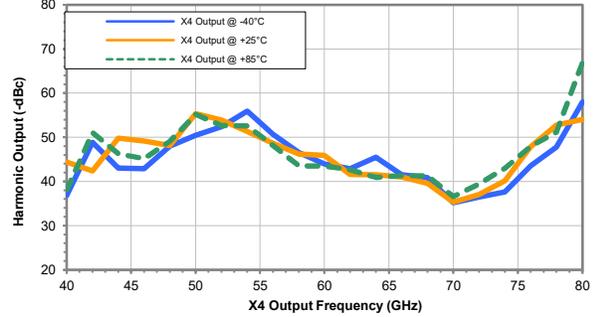Conversion Loss X3 Output Vs Pin — Temperature = +25°C

Conversion Loss X3 Output Vs Pin — Temperature = +25°C

Harmonic X1 Output Vs Pin — Temperature = +25°C

Harmonic X2 Output Vs Pin — Temperature = +25°C

Harmonic X4 Output Vs Pin — Temperature = +25°C

TYPICAL PERFORMANCE CURVES

Note: Harmonics data is presented as the harmonic of input frequency below the power of F3

Conversion Loss X3 Output Vs Temperature
RF In = +17dBm

Legend:
- Conversion Loss X3 Output @ -40°C
- Conversion Loss X3 Output @ +25°C
- Conversion Loss X3 Output @ +85°C

X-axis: X3 Output Frequency (GHz)
Y-axis: Conversion Loss (dB)

Harmonic X1 Output Vs Temperature
RF In = +17dBm

Legend:
- X1 Output @ -40°C
- X1 Output @ +25°C
- X1 Output @ +85°C

X-axis: X1 Output Frequency (GHz)
Y-axis: Harmonic Output (-dBc)

Harmonic X2 Output Vs Temperature
RF In = +17dBm

Legend:
- X2 Output @ -40°C
- X2 Output @ +25°C
- X2 Output @ +85°C

X-axis: X2 Output Frequency (GHz)
Y-axis: Harmonic Output (-dBc)

Harmonic X4 Output Vs Temperature
RF In = +17dBm

Legend:
- X4 Output @ -40°C
- X4 Output @ +25°C
- X4 Output @ +85°C

X-axis: X4 Output Frequency (GHz)
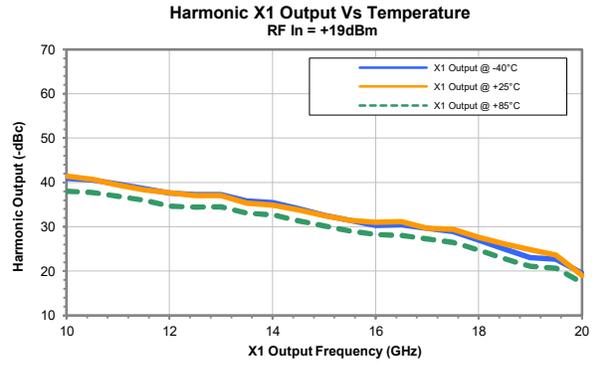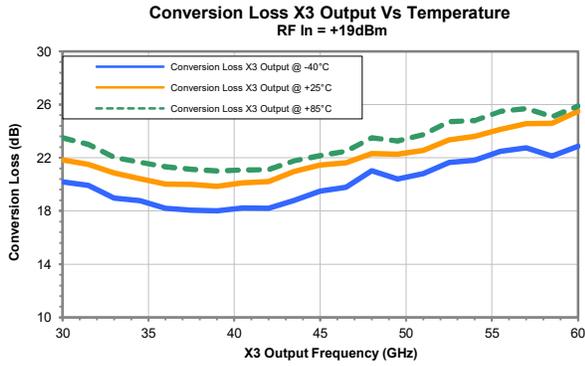Y-axis: Harmonic Output (-dBc)

X3 Frequency Multiplier   **CY3-64-D+**

50Ω   Output 30 to 60 GHz

TYPICAL PERFORMANCE CURVES

Note: Harmonics data is presented as the harmonic of input frequency below the power of F3

Conversion Loss X3 Output Vs Temperature
RF In = +18dBm

- Conversion Loss X3 Output @ -40°C
- Conversion Loss X3 Output @ +25°C
- Conversion Loss X3 Output @ +85°C

Harmonic X1 Output Vs Temperature
RF In = +18dBm

- X1 Output @ -40°C
- X1 Output @ +25°C
- X1 Output @ +85°C

Harmonic X2 Output Vs Temperature
RF In = +18dBm

- X2 Output @ -40°C
- X2 Output @ +25°C
- X2 Output @ +85°C

Harmonic X4 Output Vs Temperature
RF In = +18dBm

- X4 Output @ -40°C
- X4 Output @ +25°C
- X4 Output @ +85°C

TYPICAL PERFORMANCE CURVES

Note: Harmonics data is presented as the harmonic of input frequency below the power of F3

Conversion Loss X3 Output Vs Temperature — RF In = +19dBm
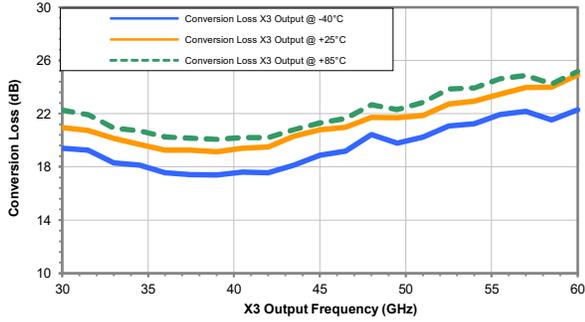
Harmonic X1 Output Vs Temperature — RF In = +19dBm

Harmonic X2 Output Vs Temperature — RF In = +19dBm

Harmonic X4 Output Vs Temperature — RF In = +19dBm

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD.

Performance Data	Data Table Swept Graphs S-Parameter (S2P Files) Data Set with and without port extension (.zip file)
Case Style	Die
Die Ordering and packaging information	Quantity, Package Model No. Gel – Pak: 5, 10, 50, 100 Medium†, Partial wafer: <506 CY3-64-DG+ Full Wafer† CY3-64-DP+ †Available upon request contact sales representative CY3-64-DF+ Refer to AN-60-067
Die Marking	EL-MUL-7
Environmental Ratings	ENV80